18020 Hobart Blvd., Unit B Gardena, CA 90248 U.S.A

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## Data Sheet No. BRDB-300-1C

## 3 AMP SILICON BRIDGE RECTIFIERS

#### **FEATURES**

- PRV Ratings from 50 to 1000 Volts
- Surge overload rating to 60 Amps peak
- Reliable low cost molded epoxy construction
- Ideal for printed circuit board applications

## **RECOGNIZED - FILE #E124962**

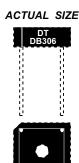
## **RoHS COMPLIANT**

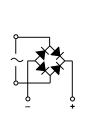
#### **MECHANICAL DATA**

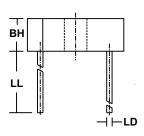
- Case: Molded Epoxy (UL Flammability Rating 94V-0)
- Terminals: Round silver plated copper pins
- Soldering: Per MIL-STD 202 Method 208 guaranteed
- Polarity: Marked on top of case; positive lead at beveled corner
- Mounting Position: Any. Thru hole provided for #6 screw (NOTE 1)
- Weight: 0.11 Ounces (3.36 Grams)

## MECHANICAL SPECIFICATION

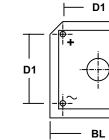
SERIES DB300-DB310







BL



SYM	MILLIM	IETERS	INCHES					
	MIN	MAX	MIN	MAX				
BL	14.7	15.7	0.58	0.62				
ВН	4.8	5.3	0.19	0.21				
D1	10.3	11.3	0.405	0.445				
LL	19.0	n/a	0.75	n/a				
LD	0.7	0.9	0.028	0.035				

#### **MAXIMUM RATINGS & ELECTRICAL CHARACTERISTICS**

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, 60Hz, resistive or inductive load. For capacitive loads, derate current by 20%.

PARAMETER (TEST CONDITIONS)	SYMBOL	RATINGS						UNITS	
Series Number		DB 300	DB 301	DB 302	DB 304	DB 306	DB 308	DB 310	
Maximum DC Blocking Voltage	<b>V</b> RM								
Working Peak Reverse Voltage		50 100	200	400	600	800	1000	VOLTS	
Maximum Peak Recurrent Reverse Voltage									
RMS Reverse Voltage	VR (RMS)	35	70	140	280	420	560	700	
Thermal Energy (Rating for Fusing) t < 8.3mSec	l²t	15					AMPS <sup>2</sup> SEC		
Peak Forward Surge Current. Single 60Hz Half-Sine Wave Superimposed on Rated Load (JEDEC Method). Tc = 60° C	IFSM	60						AMDS	
Average Forward Rectified Current @ Tc = 60°C (Note : @ T <sub>A</sub> = 25°C (Note :	3 2						AMPS		
Junction Operating and Storage Temperature Range	TJ, TSTG	-55 to +150						°C	
Maximum Forward Voltage (Per Diode) at 1.5 Amps DC		0.95 (Typical < 0.9)							
Typical Junction Capacitance (Note 4)	Cl	21						pF	
Maximum Reverse Current at Rated VRM @TA = 25° @TA = 125°		1 50						μ <b>Α</b>	
Minimum Insulation Breakdown Voltage (Circuit to Case)		2500						VOLTS	
Typical Thermal Resistance Junction to Ambient (Note Junction to Case (Note	′ I	12.0 8.0						°C/W	

NOTES: (1) Bolt bridge on heat sink with #6 screw, using silicon thermal compound between bridge and mounting surface for maximum heat transfer.
(2) Bridge mounted on 4.0" sq. x 0.11" thick (10.5cm sq. x 0.3cm) aluminum plate
(3) Bridge mounted on PC Board with 0.5" sq. (12mm sq.) copper pads and bridge lead length of 0.375" (9.5mm)
(4) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts

## DIOTEC ELECTRONICS CORP.

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# **3 AMP SILICON BRIDGE RECTIFIERS**

## **RATING & CHARACTERISTIC CURVES FOR SERIES DB300 - DB310**

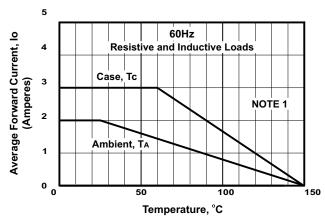


FIGURE 1. FORWARD CURRENT DERATING CURVE

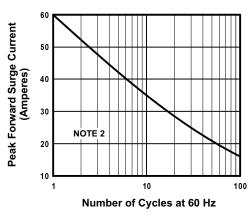


FIGURE 2. MAXIMUM NON-REPETITIVE SURGE CURRENT

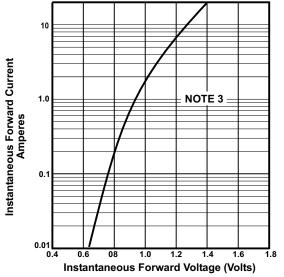
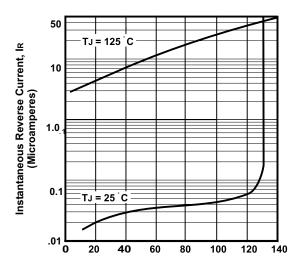


FIGURE 3. TYPICAL FORWARD CHARACTERISTIC PER DIODE



Percent of Rated Peak Reverse Voltage
FIGURE 4. TYPICAL REVERSE CHARACTERISTICS

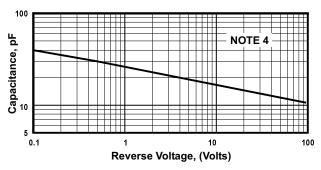


FIGURE 5. TYPICAL JUNCTION CAPACITANCE PER DIODE

### NOTES

(1) Case Temperature, Tc, With Bridge Mounted on 4" Sq. x 0.11" Thick (10.5cm Sq. x 0.3cm) Aluminum Plate

Ambient Temperature, TA. With Bridge Mounted on PC Board With 0.5" Sq. (12mm Sq.) Pads and Lead Length of 0.375" (9.5mm)

- (2)  $Tc = 60^{\circ}C$
- (3) TJ = 25°C; Pulse Width = 300 Sec; 1% Duty Cycle
- (4)  $T_J = 25^{\circ} C$ ; f = 1 MHz; Vsig = 50mVp-p

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